

TOSHIBA Intelligent Power Device Silicon Monolithic Power MOS Integrated Circuit

# TPD1024S

Low-side Power Switch for Motors, Solenoids, and Lamp Drivers

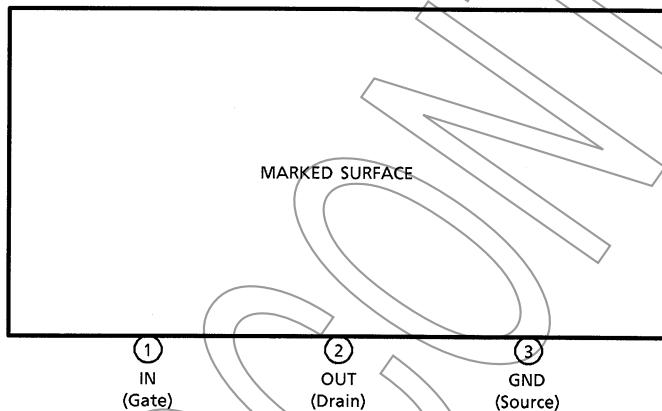
The TPD1024S is a monolithic power IC for low-side switches. The IC has a vertical MOS FET output which can be directly driven from a CMOS or TTL logic circuit (e.g., an MPU).

The device is equipped with an intelligent self-protection function.

## Features

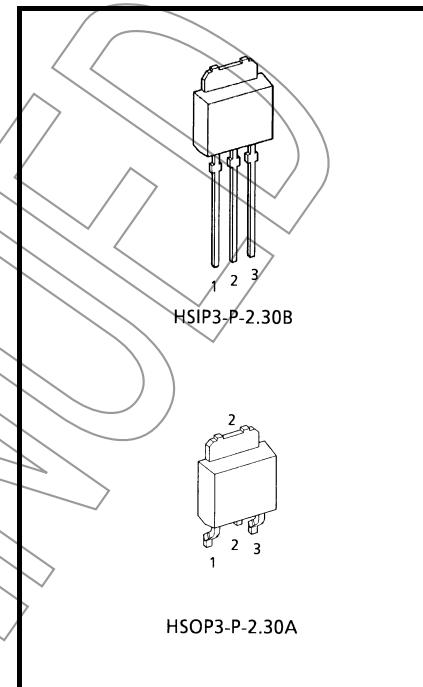
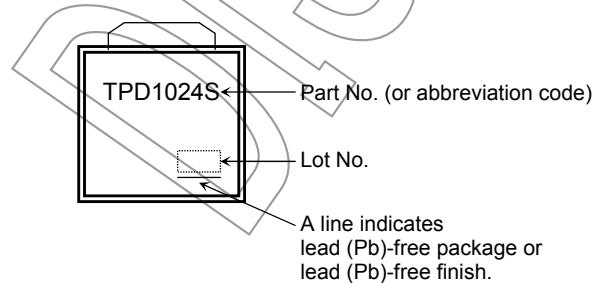
- A monolithic power IC with a new structure combining a control block and a vertical power MOS FET (n-MOS) on a single chip
- Can directly drive a power load from a CMOS logic.
- Built-in protection against overvoltage, load short-circuiting, and thermal shutdown
- Low on-resistance :  $R_{DS\ (ON)} = 0.5\ \Omega$  (max), (@ $V_{IN} = 5\ V$ ,  $T_j = 25^\circ\text{C}$ )
- 3-pin power-molded package usable for surface mounting

## Pin Assignment



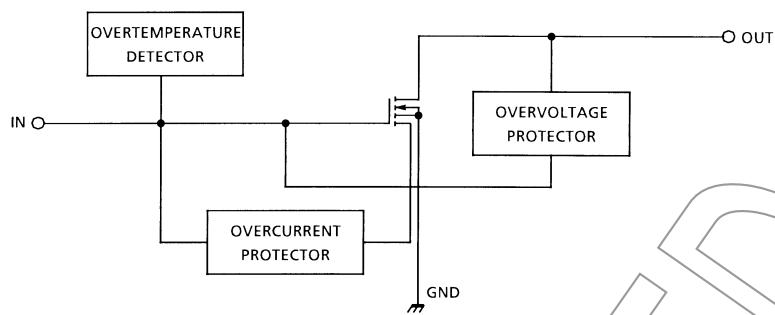
Note: Due to its MOS structure, this product is sensitive to static electricity.

## Marking



Weight	
HSIP3-P-2.30B	: 0.36 g (typ.)
HSOP3-P-2.30A	: 0.28 g (typ.)

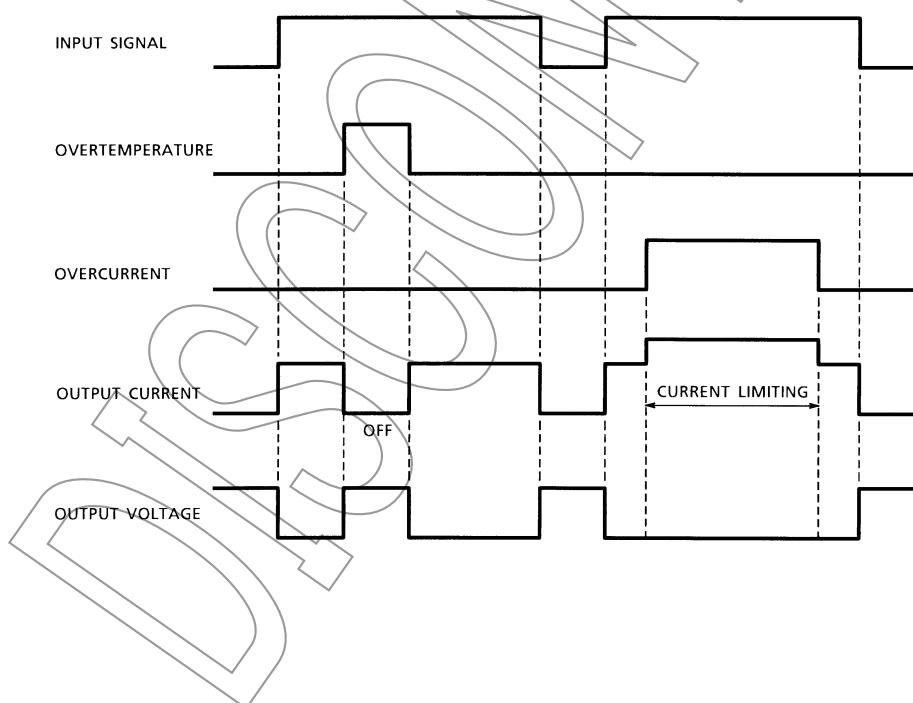
## Block Diagram



## Pin Description

Pin No.	Symbol	Function
1	IN	Input pin. Input is CMOS-compatible, with pull-down resistor connected. Even if the input is open, output will not accidentally turn on.
2	OUT	Output pin. When current in excess of the typical current (3.5 A (typ.)) flows to the output pin, the current limiter operates to protect the IC.
3	GND	Ground pin.

## Timing Chart



## Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Drain-source voltage	V <sub>DS</sub> (DC)	40	V
Output current	I <sub>D</sub>	1.5	A
Input voltage	V <sub>GS</sub>	-0.5 ~ 6	V
Power dissipation	P <sub>D</sub>	1	W
T <sub>c</sub> = 25°C	10		
Operating temperature	T <sub>opr</sub>	-40 ~ 85	°C
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 ~ 150	°C

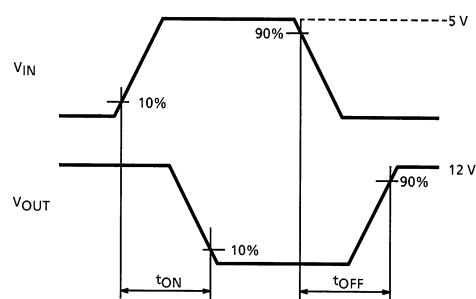
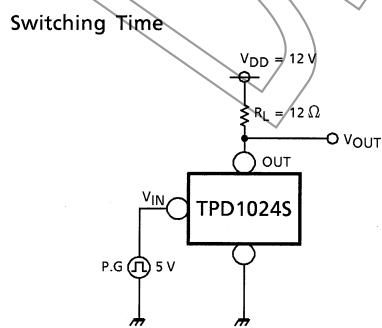
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

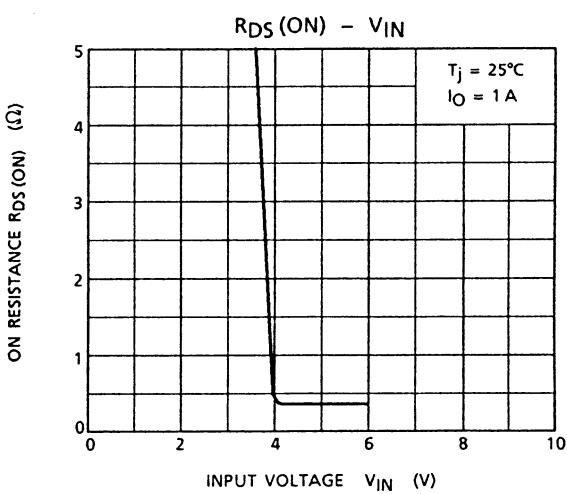
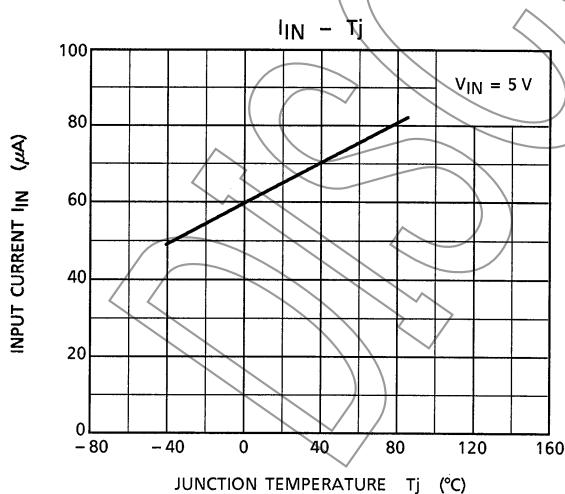
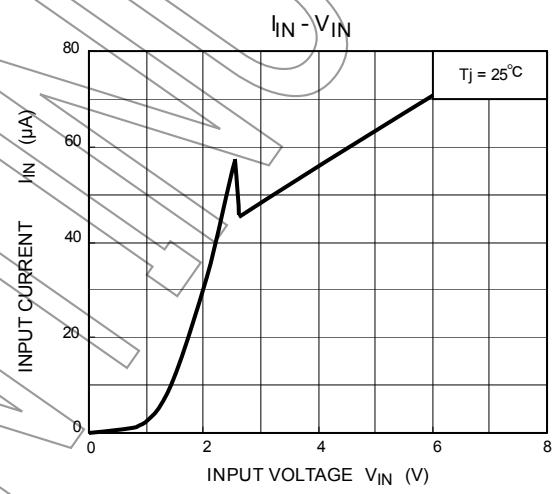
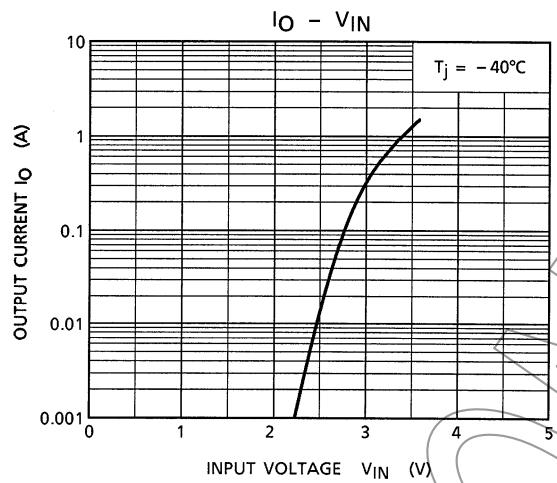
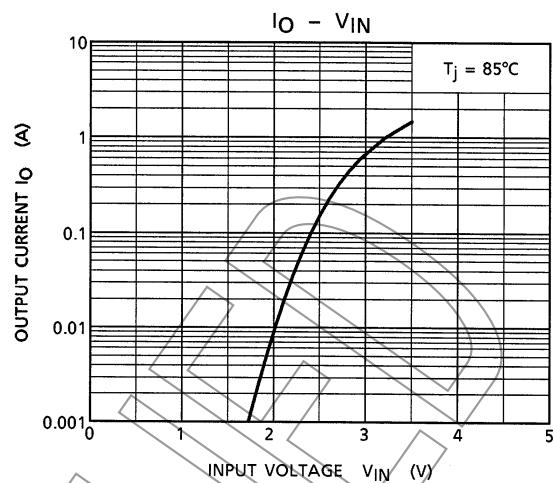
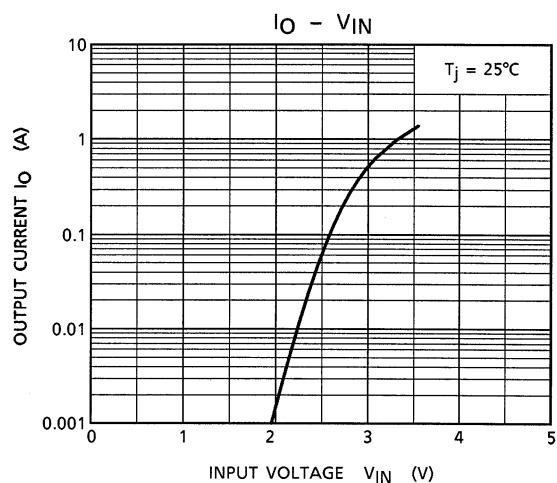
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

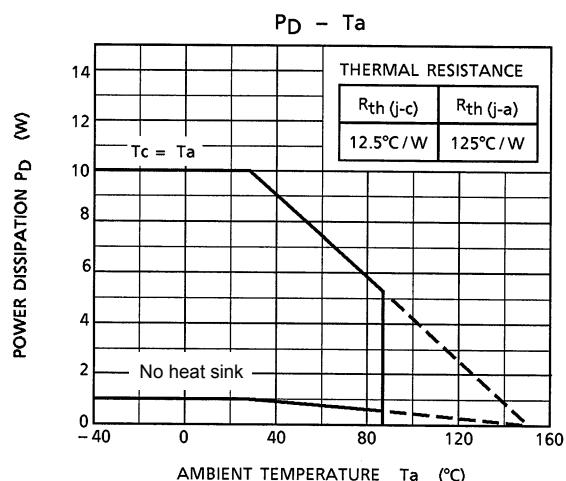
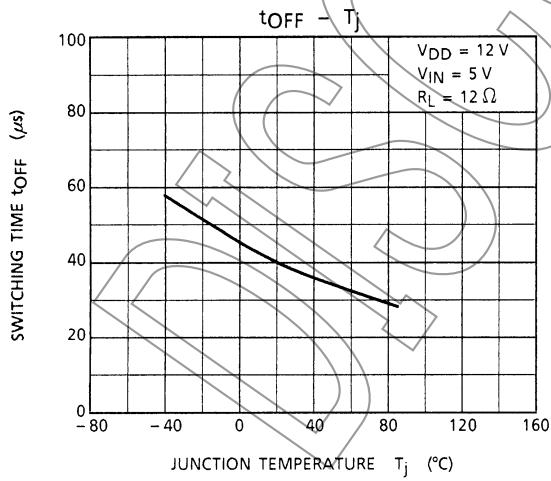
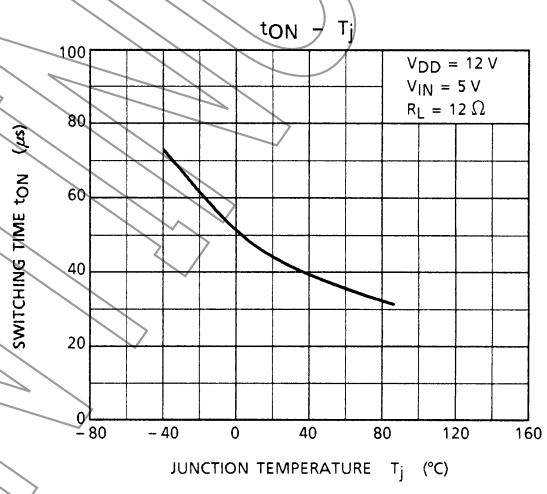
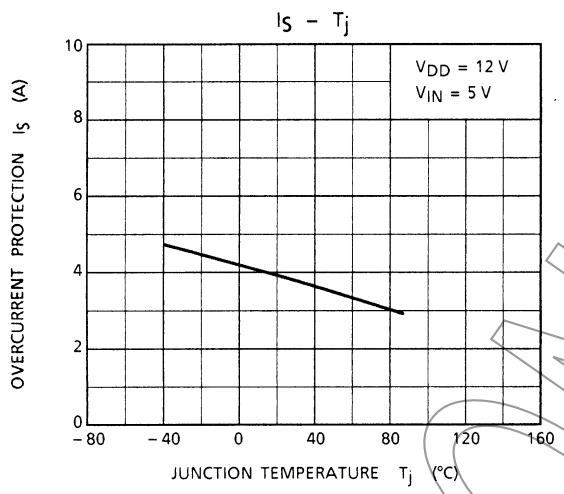
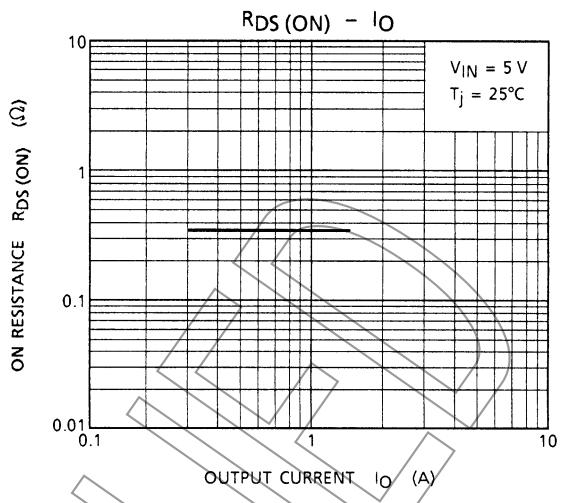
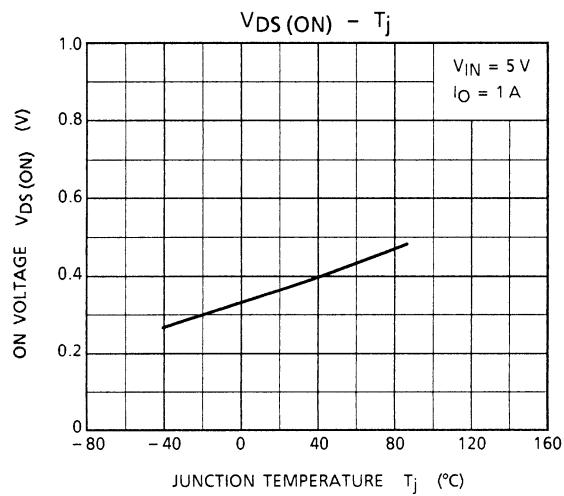
Electrical Characteristics (T<sub>j</sub> = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Drain-source breakdown voltage	V <sub>(BR) DSS</sub>	—	V <sub>GS</sub> = 0, I <sub>D</sub> = 10 mA	40	—	—	V
Operating supply voltage	V <sub>DD</sub> (OPR)	—	—	—	—	18	V
Current at output off	I <sub>DSS</sub> (1)	—	V <sub>GS</sub> = 0, V <sub>DS</sub> = 40 V	—	—	3	mA
	I <sub>DSS</sub> (2)	—	V <sub>GS</sub> = 0, V <sub>DS</sub> = 24 V	—	—	100	μA
Input threshold voltage	V <sub>th</sub>	—	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	0.8	—	2.5	V
Input current	I <sub>GSS</sub>	—	V <sub>GS</sub> = 5 V, at normal operation	—	—	300	μA
On resistance	R <sub>DS</sub> (ON)	—	V <sub>GS</sub> = 5 V, I <sub>D</sub> = 1 A	—	—	0.5	Ω
Thermal shutdown temperature	T <sub>S</sub>	—	—	—	160	—	°C
Overcurrent protection	I <sub>S</sub>	—	V <sub>DS</sub> = 12 V, V <sub>GS</sub> = 5 V	—	3.5	—	A
Switching time	t <sub>ON</sub>	1	V <sub>DS</sub> = 12 V, V <sub>GS</sub> = 5 V, R <sub>L</sub> = 12 Ω	—	50	—	μs
	t <sub>OFF</sub>			—	10	—	μs
Diode forward voltage Between drain and source	V <sub>DSF</sub>	—	I <sub>F</sub> = 1.5 A	—	0.9	1.8	V
Avalanche energy	E <sub>A</sub>	—	L = 10 mH, Single pulse	30	—	—	mJ

## Test Circuit 1



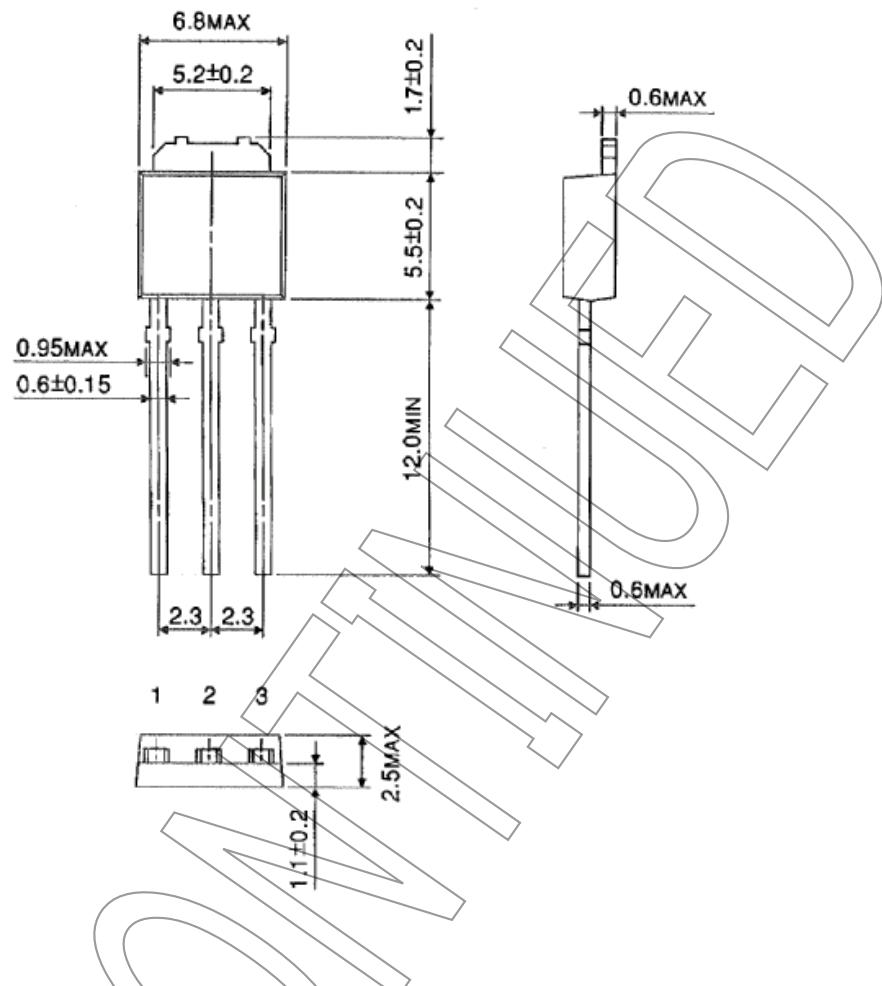




**Package Dimensions**

HSIP3\_P\_2.30B

Unit: mm

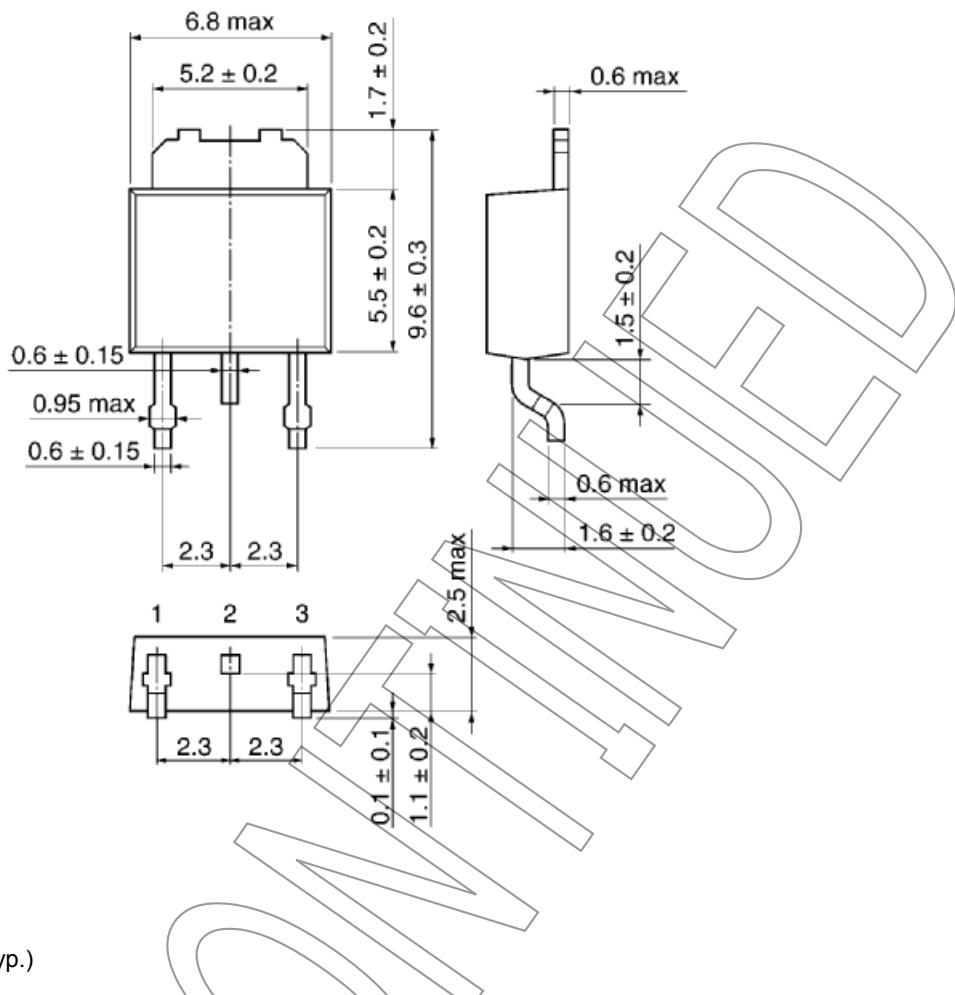


Weight: 0.36 g (typ.)

**Package Dimensions**

HSOP3\_P\_2.30A

Unit: mm



Weight: 0.28 g (typ.)

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